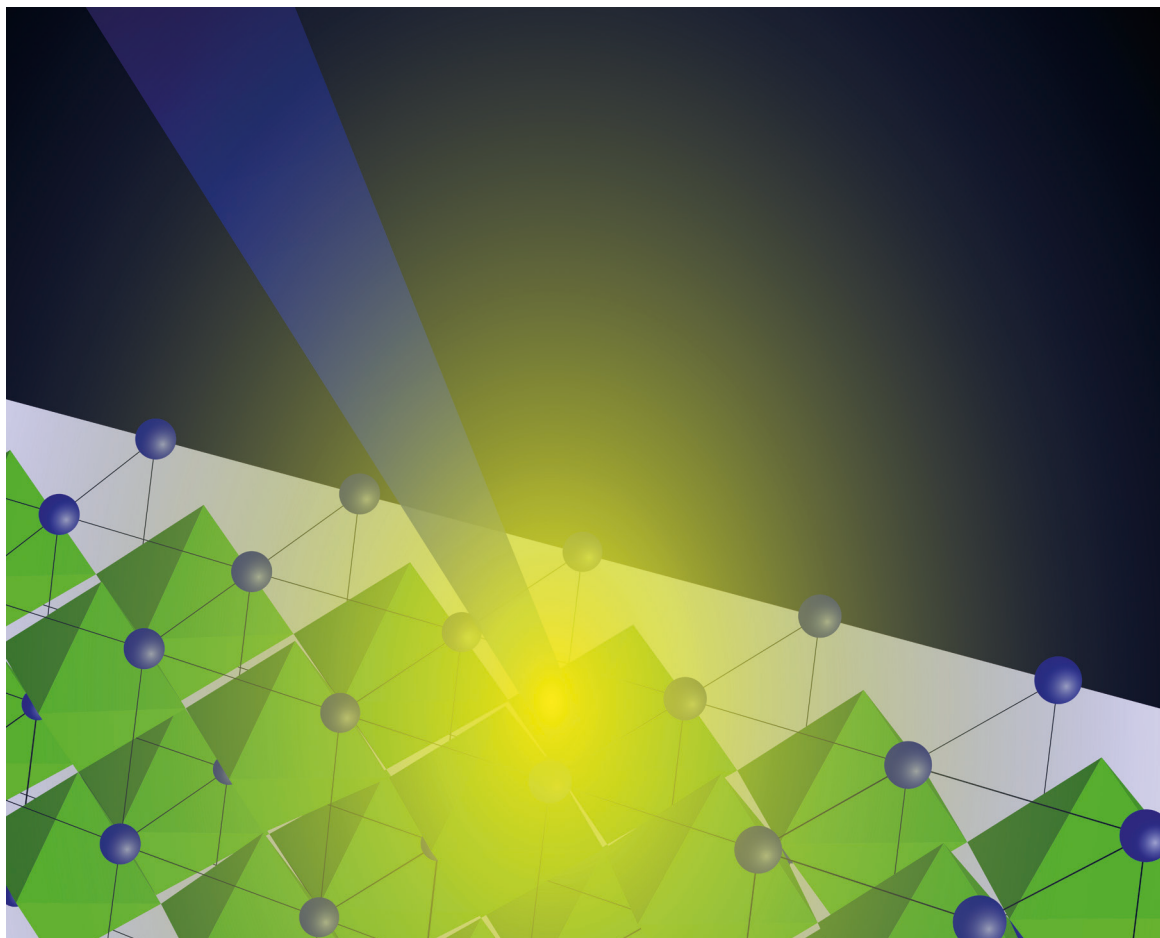




Time-Resolved Photoluminescence on Perovskite Absorber Materials for Photovoltaic Applications

Florian Staub

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